



N-Channel 250-V (D-S) MOSFET

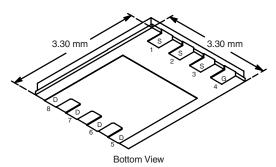
PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
250	0.435 at V _{GS} = 10 V	1.95		
	0.445 at V _{GS} = 6 V	1.9		

FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- PWM-Optimized TrenchFET[®] Power MOSFET
- Avalanche Tested
- 100 % R_q Tested

Pb-free ROHS COMPLIANT HALOGEN FREE

PowerPAK® 1212-8

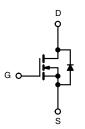


Ordering Information: Si7802DN-T1-E3 (Lead (Pb)-free)

Si7802DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

APPLICATIONS

- Primary Side Switch
- Small DC/DC Circuits
- · Single-Ended Primary Switching Circuits



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	250		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Dunin Comment /T 150 °C\	T _A = 25 °C	I _D	1.95	1.24	
Continuous Drain Current $(T_J = 150 ^{\circ}C)^a$	T _A = 70 °C		1.56	0.99	
Pulsed Drain Current		I _{DM}	8		Α
Continuous Source Current (Diode Conduction) ^a		I _S	3.2	1.3	
Single Avalanche Current	L = 0.1 mH	I _{AS}	2.5 0.3		
Single Avalanche Energy	L=0.11IIII	E _{AS}			mJ
M ·	T _A = 25 °C	ν	3.8	1.5	W
Maximum Power Dissipation ^a	T _A = 70 °C		2.0	0.8	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150 260		
Soldering Recommendations (Peak Temperature) ^{b, c}					°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manifestura Instanta Assaultinată	t ≤ 10 s	- R _{thJA}	26	33	°C/W
Maximum Junction-to-Ambient ^a	Steady State		65	81	
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	1.9	2.4	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Vishay Siliconix



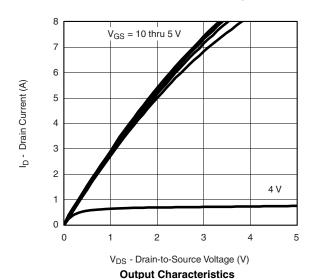
MOSFET SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.		Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.4		3.6	V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvain Current	I _{DSS}	V _{DS} = 250 V, V _{GS} = 0 V	1		1	4	
Zero Gate Voltage Drain Current		V _{DS} = 250 V, V _{GS} = 0 V, T _J = 55 °C			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	8			Α	
	В	V _{GS} = 10 V, I _D = 1.95 A		0.360	0.435	0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 6 \text{ V}, I_D = 1.9 \text{ A}$		0.370	0.445	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 1.95 A		8		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 3.2 A, V _{GS} = 0 V		0.8	1.2	V	
Dynamic ^b			•	•			
Total Gate Charge	Q_g			14	21	nC	
Gate-Source Charge	Q_{gs}	$V_{DS} = 125 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 1.95 \text{ A}$		2.8			
Gate-Drain Charge	Q_{gd}			4.4			
Gate Resistance	R_{g}	f = 1MHz		1.6	2.4	Ω	
Turn-On Delay Time	t _{d(on)}			10	15		
Rise Time	t _r	V_{DD} = 125 V, R_{L} = 1.25 Ω		10	15		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		21	35	ns	
Fall Time	t _f			12	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 3.2 A, dI/dt = 100 A/μs		65	100		

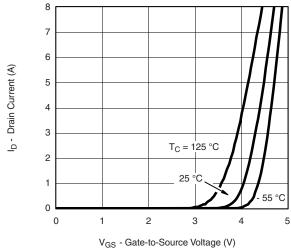
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





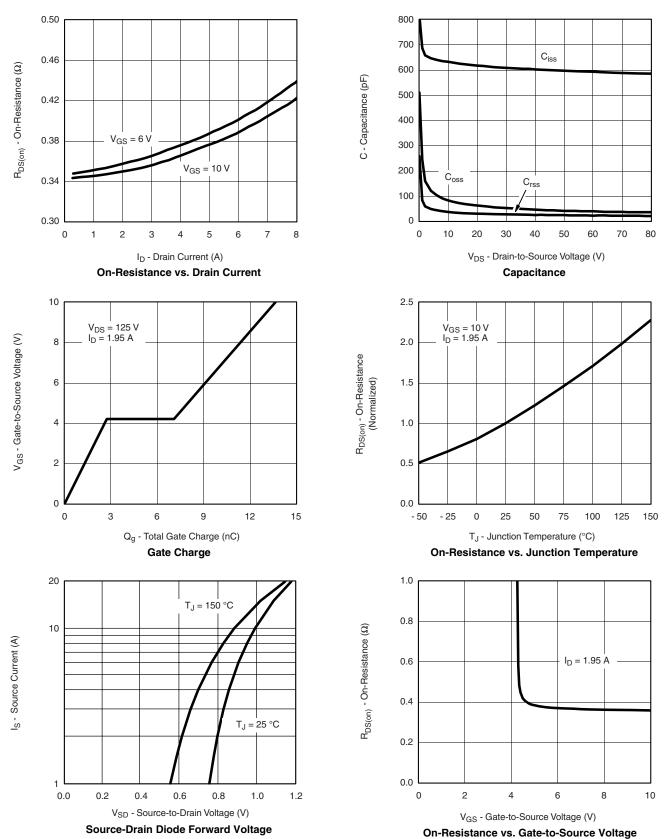
Transfer Characteristics







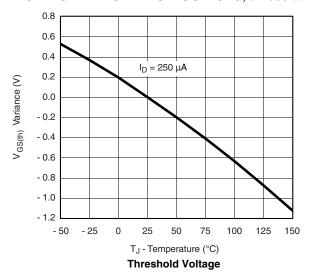
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

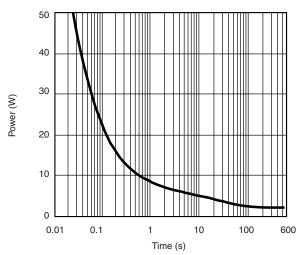


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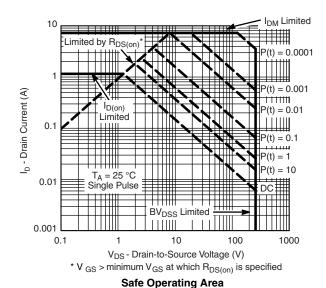
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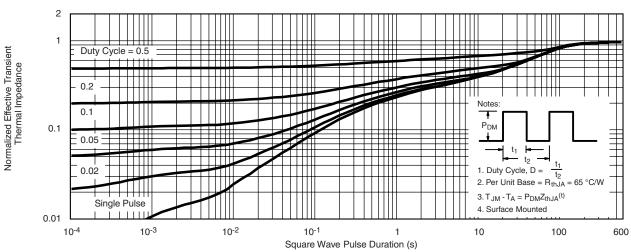
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Single Pulse Power, Junction-to-Ambient





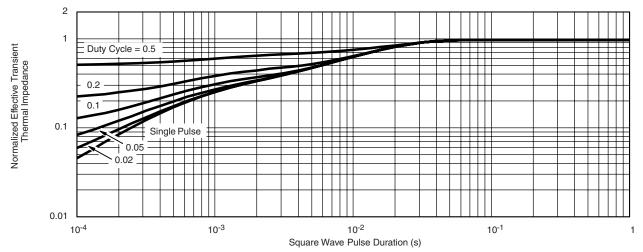
Normalized Thermal Transient Impedance, Junction-to-Ambient







TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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